

N-P-N SILICON PLANAR DARLINGTON TRANSISTORS

BDX42
BDX43
BDX44

TENTATIVE DATA

Silicon n-p-n planar Darlington transistors for industrial switching applications, e.g. print hammer, solenoid, relay and lamp driving. Encapsulated in a TO-126 plastic envelope with collector connected to the heatsink.

QUICK REFERENCE DATA

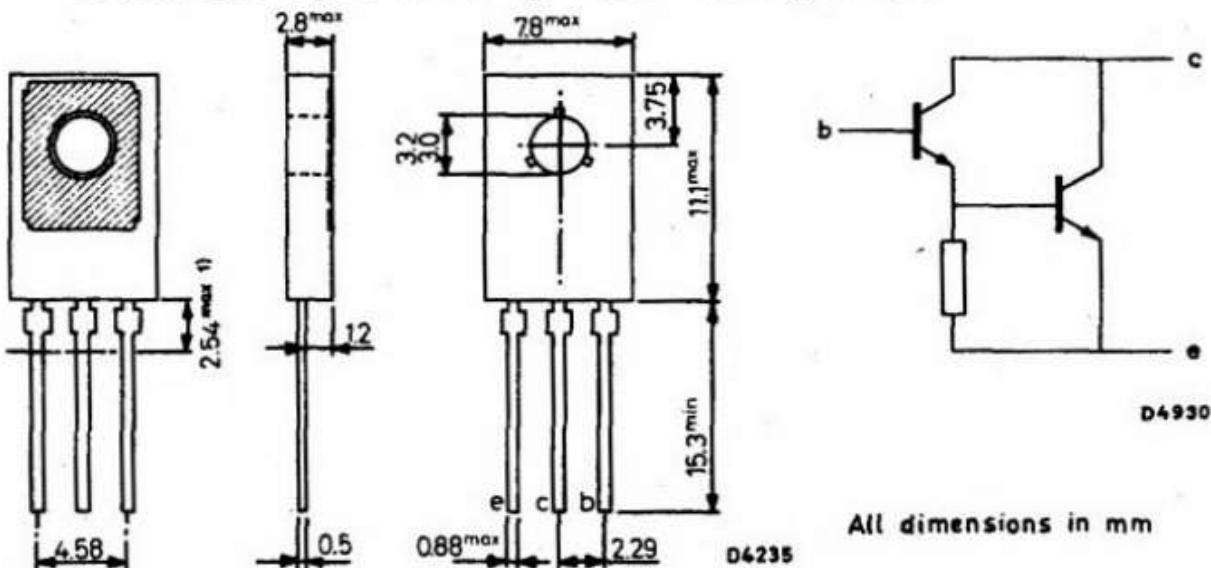
	BDX42	BDX43	BDX44	
V_{CBO} max.	60	80	100	V
V_{CE} max.	45	60	80	V
I_C max.	1.0	1.0	1.0	A
P_{tot} max. ($T_{amb} \leq 25^\circ C$)	1.25	1.25	1.25	W
P_{tot} max. ($T_{mb} \leq 100^\circ C$)	5.0	5.0	5.0	W
h_{FE} min. ($I_C = 500mA$, $V_{CE} = 10V$)	1500	1500	1500	
$V_{CE(sat)}$ max. ($I_C = 1.0A$, $I_B = 1.0mA$)	-	1.6	-	V
$V_{CE(sat)}$ max. ($I_C = 1.0A$, $I_B = 4.0mA$)	1.6	-	1.6	V
t_{off} typ. ($I_C = 500mA$, $I_{B(on)} = -I_{B(off)} = 0.5mA$)	1000	1000	1000	ns

Unless otherwise stated data are applicable to all types.

OUTLINE AND DIMENSIONS

Conforms to J.E.D.E.C. TO-126

Collector connected to the metal part of the mounting surface



1) Within this region the cross-section of the leads is uncontrolled

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RATINGS

Limiting values of operation according to the absolute maximum system.

Electrical

	BDX42	BDX43	BDX44	
V_{CBO} max.	60	80	100	V
V_{CE} max. (Max. external R_{BE} 100k Ω) at $T_j = 150^\circ\text{C}$	45	60	80	V
V_{EBO} max.	5.0	5.0	5.0	V
I_C max.	1.0	1.0	1.0	A
I_B max.	0.1	0.1	0.1	A
P_{tot} max. ($T_{amb} \leq 25^\circ\text{C}$)	1.25	1.25	1.25	W
P_{tot} max. ($T_{mb} \leq 100^\circ\text{C}$)	5.0	5.0	5.0	W
Temperature				
T_{stg} range	-65 to +150			$^\circ\text{C}$
T_j max.	150			$^\circ\text{C}$

THERMAL CHARACTERISTICS

	100	$^\circ\text{C}/\text{W}$
$R_{th(j-amb)}$	10	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$ unless otherwise stated)

		Min.	Typ.	Max.		
I_{CBO}	Collector cut-off current $V_{CB} = 45\text{V}, I_E = 0$	BDX42	-	-	100 nA	
	$V_{CB} = 60\text{V}, I_E = 0$	BDX43	-	-	100 nA	
	$V_{CB} = 80\text{V}, I_E = 0$	BDX44	-	-	100 nA	
I_{EBO}	Emitter cut-off current $V_{EB} = 4.0\text{V}, I_C = 0$	-	-	100	nA	
h_{FE}	Static forward current transfer ratio $I_C = 150\text{mA}, V_{CE} = 10\text{V}$	1000	-	-		
	$I_C = 500\text{mA}, V_{CE} = 10\text{V}$	1500	-	-		
$V_{CE(sat)}$	Collector-emitter saturation voltage $I_C = 500\text{mA}, I_B = 0.5\text{mA}$	-	-	1.3	V	
	$I_C = 1.0\text{A}, I_B = 1.0\text{mA}$	BDX43	-	-	1.6	V
	$I_C = 1.0\text{A}, I_B = 4.0\text{mA}$	BDX42	-	-	1.6	V
		BDX44	-	-	1.6	V

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ELECTRICAL CHARACTERISTICS (Contd.)

		Min.	Typ.	Max.	
	$I_C = 500\text{mA}, I_B = 0.5\text{mA}, T_j = 150^\circ\text{C}$	-	-	1.3	V
	$I_C = 1.0\text{A}, I_B = 1.0\text{mA}, T_j = 150^\circ\text{C}$	BDX43	-	1.8	V
	$I_C = 1.0\text{A}, I_B = 4.0\text{mA}, T_j = 150^\circ\text{C}$	BDX42	-	1.6	V
		BDX44	-	1.6	V
$V_{BE(\text{sat})}$	Base-emitter saturation voltage				
	$I_C = 500\text{mA}, I_B = 0.5\text{mA}$	-	-	1.9	V
	$I_C = 1.0\text{A}, I_B = 1.0\text{mA}$	BDX43	-	2.2	V
	$I_C = 1.0\text{A}, I_B = 4.0\text{mA}$	BDX42	-	2.2	V
		BDX44	-	2.2	V
h_{fe}	Small signal forward current transfer ratio				
	$I_C = 0.5\text{A}, V_{CE} = 5.0\text{V}, f = 35\text{MHz}$	7.5	10	-	

Switching times (see also page 4):

	$I_C = 500\text{mA}, I_{B(on)} = -I_{B(off)} = 0.5\text{mA}$				
t_{on}	Turn-on time	-	-	400	ns
t_{off}	Turn-off time	-	1000	2000	ns
	$I_C = 1.0\text{A}, I_{B(on)} = -I_{B(off)} = 1.0\text{mA}$				
t_{on}	Turn-on time	-	-	400	ns
t_{off}	Turn-off time	-	1000	2000	ns

MECHANICAL DATA

Maximum torque on nut	4.0	kg cm
	0.4	Nm
Minimum torque on nut for good thermal contact	3.0	kg cm
	0.3	N m

ACCESSORIES

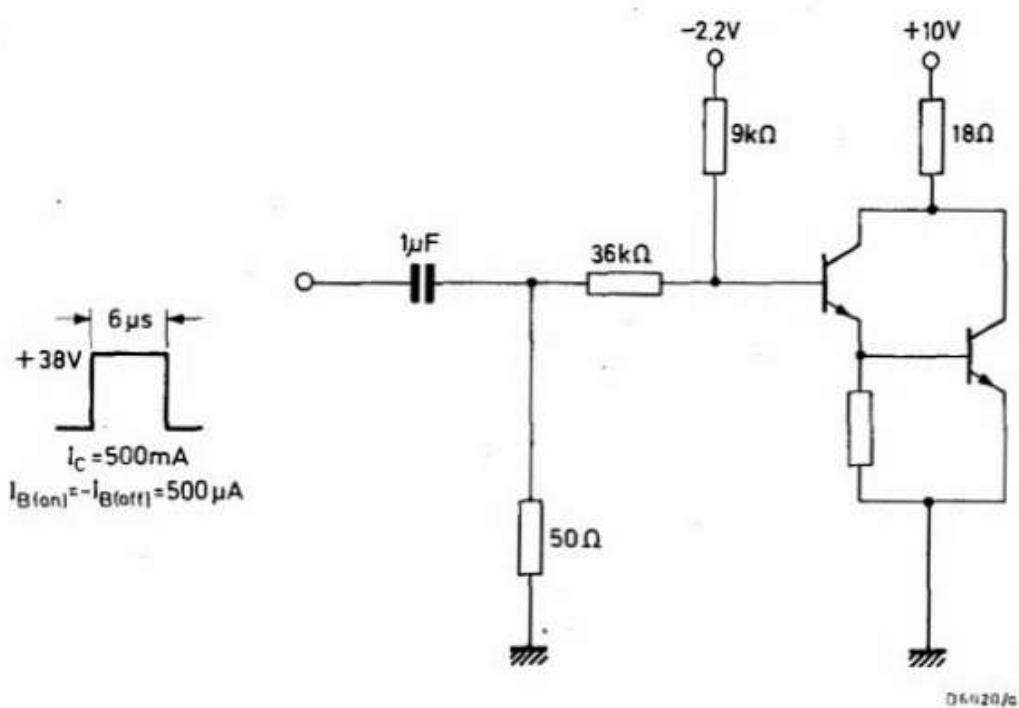
Accessory	Code No.	Note
1 Mica washer	56301B	
1 Plain washer	56326	Supplied on request

When mounted on a heatsink it is essential that a plain washer be used to prevent damage to the devices while tightening the mounting screw.

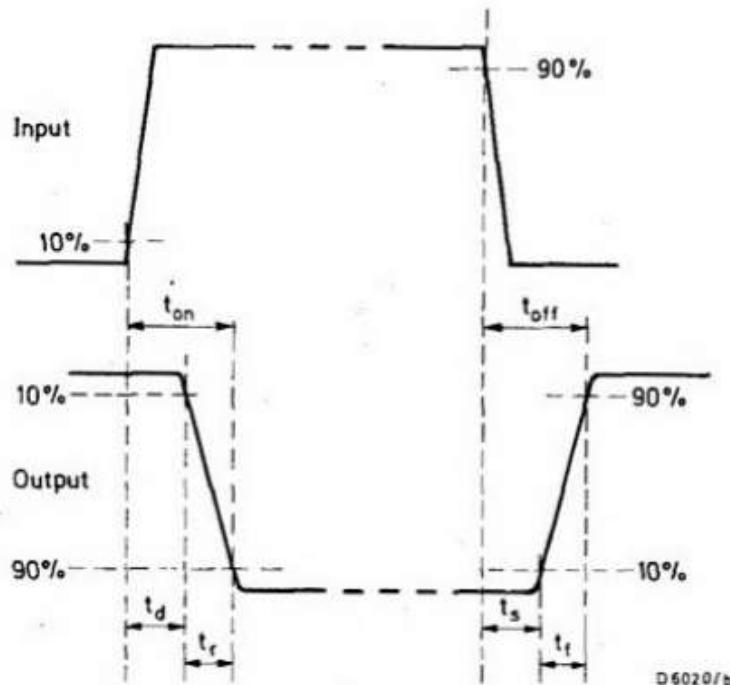
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MEASUREMENT OF SATURATED SWITCHING TIMES

Test circuit for 500mA switching.



Switching waveforms



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